

## Features

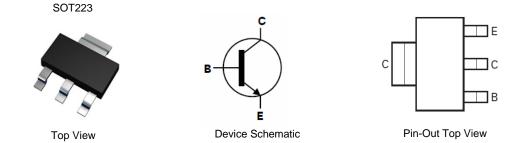
- BV<sub>CEO</sub> > 60V
- I<sub>C</sub> = 6A Continuous Collector Current
- I<sub>CM</sub> = 20A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(SAT)</sub> < 60mV Max @ 1A</li>
- $R_{SAT} = 35m\Omega @ I_c = 6A$  for Low Equivalent On-Resistance
- hFE Specified up to 10A for High Gain Hold Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

# Applications

- Emergency Lighting Circuits
- Motor Driving (Including DC Fans)
- Solenoid, Relay and Actuator Drivers
- DC Modules
- Backlight Inverters



### Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel	
ZXTN2010GTA	ZXTN2010GTA ZXTN2010		12	1,000	
Natas: 1 ELL Directive 2002/05/EC (Pauls) & 2011/65/ELL (Pauls 2) compliant. All applicable Pauls exemptions applied					

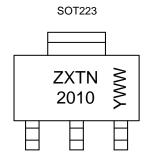
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



ZXTN 2010 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 5= 2015) WW or  $\overline{WW}$  = Week Code (01~53)



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	lc	6	А
Peak Pulse Current	I <sub>CM</sub>	20	А

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)		3.0 24	W	
Linear Derating Factor	(Note 6)	P <sub>D</sub>	1.6 12.8	mW/°C	
Thermal Desistance, Junction to Ambient	(Note 5)	R <sub>0JA</sub>	42		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ ext{ heta}JA}$	78	°C/W	
Thermal Resistance, Junction to Lead	(Note 7)	R <sub>θJL</sub>	8.8		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

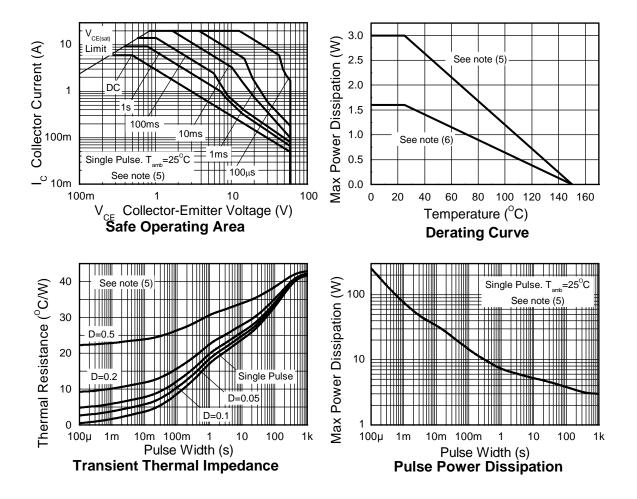
## ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air 6. Same as Note 5, except the device is mounted on 25mm x 52mm 20z copper that is conditions whilst operating in steady-state.
6. Same as Note 5, except the device is mounted on 25mm x 25mm 10z copper.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**





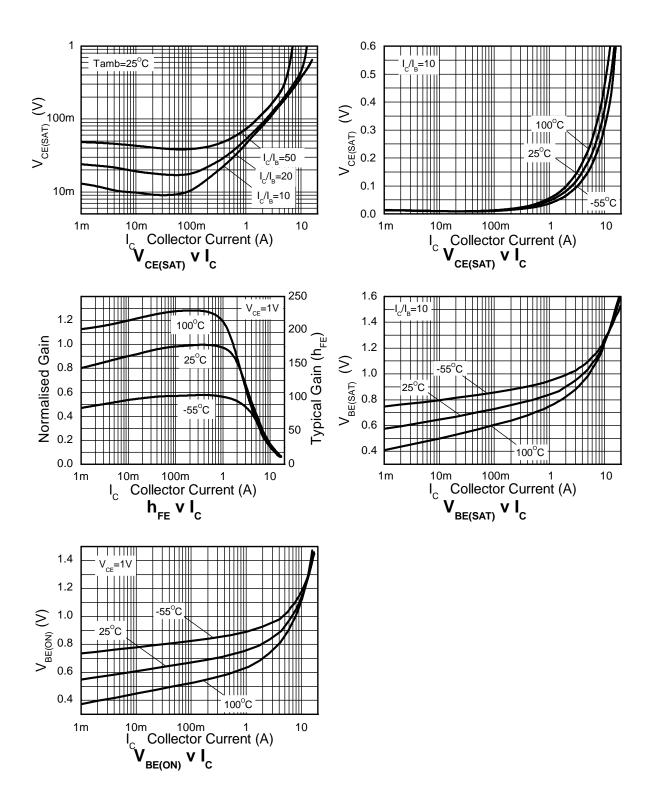
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		150	190	_	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage		150	190	_	V	I <sub>C</sub> = 1μA, RB ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	60	80	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BVEBO	7	8.1	_	V	I <sub>E</sub> = 100μA
Collector Cut-Off Current	I <sub>CBO</sub>	_	_	50 0.5	nA μA	V <sub>CB</sub> = 120V V <sub>CB</sub> = 120V, T <sub>A</sub> = +100°C
Collector Cut-Off Current	I <sub>CER</sub> R≤1kΩ	_	_	100 0.5	nA μA	V <sub>CB</sub> = 120V V <sub>CB</sub> = 120V, T <sub>A</sub> = +100°C
Emitter Cut-Off Current	IEBO	_	—	10	nA	$V_{EB} = 6V$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>		20 45 50 100 210	30 60 70 135 260	mV	$\begin{split} I_{C} &= 0.1A, \ I_{B} = 5mA \\ I_{C} &= 1A, \ I_{B} = 100mA \\ I_{C} &= 1A, \ I_{B} = 50mA \\ I_{C} &= 2A, \ I_{B} = 50mA \\ I_{C} &= 6A, \ I_{B} = 300mA \end{split}$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	_	1	1.1	V	I <sub>C</sub> = 6A, I <sub>B</sub> = 300mA
Base-Emitter Turn-on Voltage (Note 9)	V <sub>BE(on)</sub>	_	0.94	1.05	V	$I_{C} = 6A, V_{CE} = 1V$
DC Current Gain (Note 9)	hFE	100 100 55 20	200 200 105 40	 300 		$\label{eq:lc} \begin{array}{l} I_{C} = 10mA,  V_{CE} = 1V \\ I_{C} = 2A,  V_{CE} = 1V \\ I_{C} = 5A,  V_{CE} = 1V \\ I_{C} = 10A,  V_{CE} = 1V \end{array}$
Transition Frequency	f <sub>T</sub>	_	130	_	MHz	$V_{CE} = 10V$ , $I_C = 100mA$ , f = 50MHz
Output Capacitance (Note 9)	C <sub>obo</sub>		31	_	pF	$V_{CB} = 10V, f = 1MHz$
Switching Times	t <sub>ON</sub> toff	_	42 760	_	ns	$V_{CC} = 10V, I_C = 1A,$ $I_{B1} = -I_{B2} = 100mA$

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

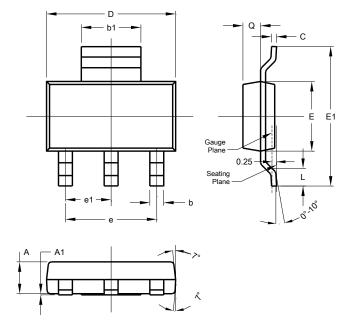




# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

SOT223

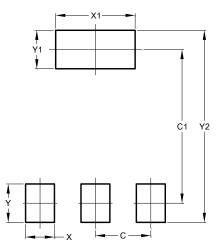


	SOT223					
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
E	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All [	All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

SOT223



Dimensions	Value (in mm)			
С	2.30			
C1	6.40			
Х	1.20			
X1	3.30			
Y	1.60			
Y1	1.60			
Y2	8.00			



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